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Renesas Technology Corp. Customer Support Dept. April 1, 2003



MITSUBISHI MICROCOMPUTERS M37733S4BFP



16-BIT CMOS MICROCOMPUTER

DESCRIPTION

The M37733S4BFP is a microcomputer using the 7700 Family core. This microcomputer has a CPU and a bus interface unit. The CPU is a 16-bit parallel processor that can be an 8-bit parallel processor, and the bus interface unit enhances the memory access efficiency to execute instructions fast. This microcomputer also includes a 32 kHz oscillation circuit, in addition to the RAM, multiple-function timers, serial I/O, A-D converter, and so on.

FEATURES

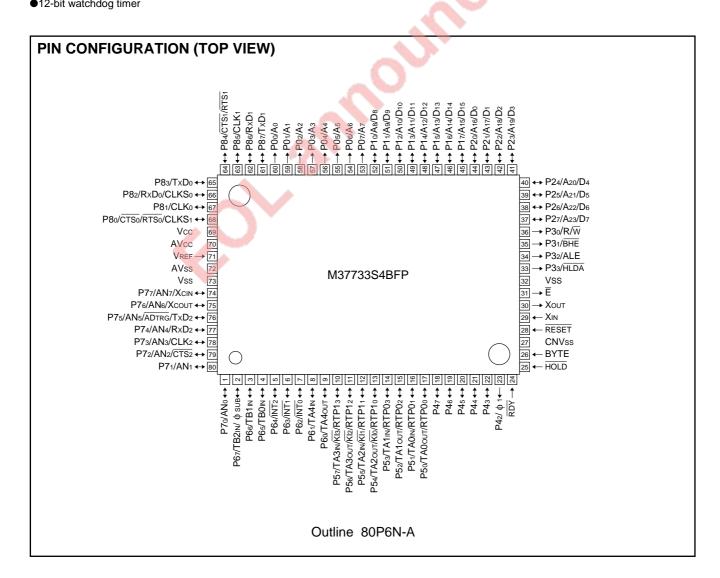
Number of basic	instructions	103
Memory size	RAM	2048 bytes
●Instruction execu	ition time	
The fastest instru	uction at 25 MHz frequency	160 ns
●Single power sup	pply	5 V ± 10 %
●Low power dissip	pation (At 25 MHz frequency).	47.5 mW (Typ.)
●Interrupts		19 types, 7 levels
Multiple-function	16-bit timer	5 + 3
●Serial I/O (UART	or clock synchronous)	3
●10-bit A-D conve	rter	8-channel inputs
■12-bit watchdog	timer	

●Programmable input/output	
(ports P4, P5, P6, P7, P8)	37
Clock generating circuit	2 circuits built-in

APPLICATION

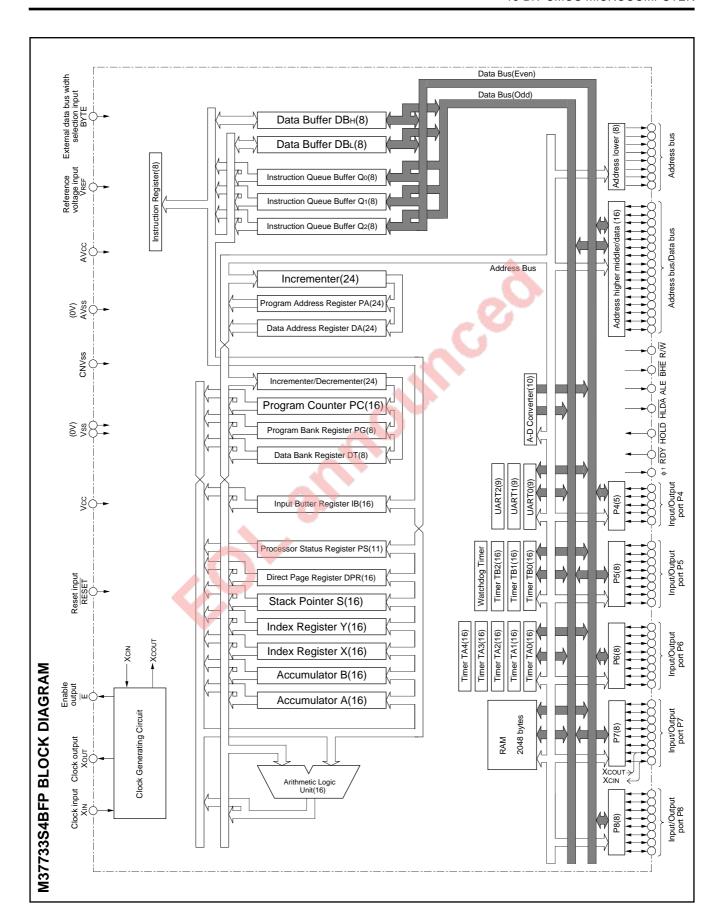
Control devices for general commercial equipment such as office automation, office equipment, personal information equipment, and so on

Control devices for general industrial equipment such as communication equipment, and so on.









M37733S4BFP



16-BIT CMOS MICROCOMPUTER

FUNCTIONS OF M37733S4BFP

	Parameter	Functions		
Number of basic instructions		103		
Instruction execution time		160 ns (the fastest instruction at external clock 25 MHz frequency)		
Memory size	RAM	2048 bytes		
Input/Output ports	P5 – P8	8-bit X 4		
mpas Gatpat porto	P4	5-bit X 1		
Multi-function timers	TA0, TA1, TA2, TA3, TA4	16-bit X 5		
wulli-lunction timers	TB0, TB1, TB2	16-bit X 3		
Serial I/O	rial I/O (UART or clock synchronous serial I/O) X 3			
A-D converter 10-bit X 1 (8 channels)		10-bit X 1 (8 channels)		
Watchdog timer		12-bit X 1		
Interrupte		3 external types, 16 internal types		
Interrupts		Each interrupt can be set to the priority level $(0-7.)$		
Clock generating circuit		2 circuits built-in (externally connected to a ceramic resonator or a quartz-crystal oscillator)		
Supply voltage		5 V ± 10 %		
Power dissipation		47.5 mW (at external clock 25 MHz frequency)		
land to the state of the state	Input/Output voltage	5 V		
Input/Output characteristic	Output current	5 mA		
Memory expansion	•	Maximum 16 Mbytes		
Operating temperature range		−20 to 85 °C		
Device structure		CMOS high-performance silicon gate process		
Package		80-pin plastic molded QFP (80P6N-A)		





PIN DESCRIPTION

Pin	Name	Input/Output	Functions
Vcc,	Power source		Apply 5 V \pm 10 % to Vcc and 0 V to Vss.
Vss			
CNVss	CNVss input	Input	Connect to Vcc.
RESET	Reset input	Input	When "L" level is applied to this pin, the microcomputer enters the reset state.
XIN	Clock input	Input	These are pins of main-clock generating circuit. Connect a ceramic resonator or a quartz-crystal oscillator between XIN and XOUT. When an external clock is used, the clock source should be
Хоит	Clock output	Output	connected to the XIN pin, and the XOUT pin should be left open.
E	Enable output	·	When output level of E signal is "L", data/instruction read or data write is performed.
BYTE	Bus width selection input	Input	This pin determines whether the external data bus has an 8-bit width or a 16-bit width. The data bus has a 16-bit width when "L" signal is input and an 8-bit width when "H" signal is input.
AVcc,	Analog power		Power source input pin for the A-D converter. Externally connect AVcc to Vcc and AVss to Vss.
AVss	source input		
VREF	Reference	Input	This is reference voltage input pin for the A-D converter.
D0-/A-	voltage input	Out to the	Address (As As) is suffered
P00/A0 – P07/A7	Address (low- order) output	Output	Address (Ao – A7) is output.
P10/A8/D8 – P17/A15/D15	Address (middle -order) output/data (high-order) I/O	I/O	When the BYTE pin is set to "L" and external data bus has a 16-bit width, high-order data (D8 – D15) is input/output or an address (A8 – A15) is output. When the BYTE pin is "H" and an external data bus has an 8-bit width, only address (A8 – A15) is output.
P20/A16/D0 — P27/A23/D7	Address (high- order) output/data (low-order) I/O	I/O	Low-order data (D ₀ – D ₇) is input/output or an address (A ₁₆ – A ₂₃) is output.
P3o/R/W	Read/Write output	Output	"H" indicates the read status and "L" indicates the write status.
P31/BHE	Byte high enable output	Output	"L" is output when an odd-numbered address is accessed.
P32/ALE	Address latch enable output	Output	This is used to retrieve only the address from address and data multiplex signal.
P33/HLDA	Hold acknow- ledge output	Output	This outputs "L" level when the microcomputer enters hold state after a hold request is accepted.
HOLD	Hold request input	Input	This is an input pin for HOLD request signal. The microcomputer enters into hold state while this signal is "L".
RDY	Ready input	Input	This is an input pin for RDY signal. The microcomputer enters into ready state while this signal is "L".
P42/ ф 1	Clock output	Output	This pin outputs the clock \$\phi\$ 1.
P43 – P47	I/O port P4	1/0	These pins become a 5-bit I/O port. An I/O direction register is available so that each pin can be programmed for input or output. These ports are in the input mode when reset.
P50 – P57	I/O port P5	I/O	In addition to having the same functions as port P4, these pins also function as I/O pins for timers A0 to A3 and input pins for key input interrupt input $(\overline{Kl_0} - \overline{Kl_3})$.
P60 – P67	I/O port P6	I/O	In addition to having the same functions as port P4, these pins also function as I/O pins for timer A4, input pins for external interrupt input $(\overline{INT_0} - \overline{INT_2})$ and input pins for timers B0 to B2. P67 also functions as sub-clock ϕ SUB output pin.
P70 – P77	I/O port P7	I/O	In addition to having the same functions as port P4, these pins function as input pins for A-D converter. P72 to P75 also function as I/O pins for UART2. Additionally, P76 and P77 have the function as the output pin (XCOUT) and the input pin (XCN) of the sub-clock (32 kHz) oscillation circuit, respectively. When P76 and P77 are used as the XCOUT and XCIN pins, connect a resonator or an oscillator between the both.
P8 ₀ – P8 ₇	I/O port P8	I/O	In addition to having the same functions as port P4, these pins also function as I/O pins for UART 0 and UART 1.



M37733S4BFP



16-BIT CMOS MICROCOMPUTER

BASIC FUNCTION BLOCKS

The M37733S4BFP has the same functions as the M37733MHBXXXFP except for the following:

- (1) The memory map is different.
- (2) The processor mode is different.
- (3) The reset circuit is different.
- (4) Pulse output port mode of timer A is available.
- (5) The function of ROM area modification is not available.

MEMORY

The memory map is shown in Figure 1. The address space has a capacity of 16 Mbytes and is allocated to addresses from 016 to FFFFFF16. The address space is divided by 64-Kbyte unit called bank. The banks are numbered from 016 to FF16.

Built-in RAM and control registers for internal peripheral devices are assigned to bank 016.

Addresses FFD616 to FFFF16 are the RESET and interrupt vector addresses and contain the interrupt vectors. Use ROM for memory of this address

The 2048-byte area allocated to addresses from 8016 to 87F16 is the built-in RAM. In addition to storing data, the RAM is used as stack during a subroutine call or interrupts.

Peripheral devices such as I/O ports, A-D converter, serial I/O, timer, and interrupt control registers are allocated to addresses from 016 to 7F16.

A 256-byte direct page area can be allocated anywhere in bank 016 by using the direct page register (DPR). In the direct page addressing mode, the memory in the direct page area can be accessed with two words. Hence program steps can be reduced.

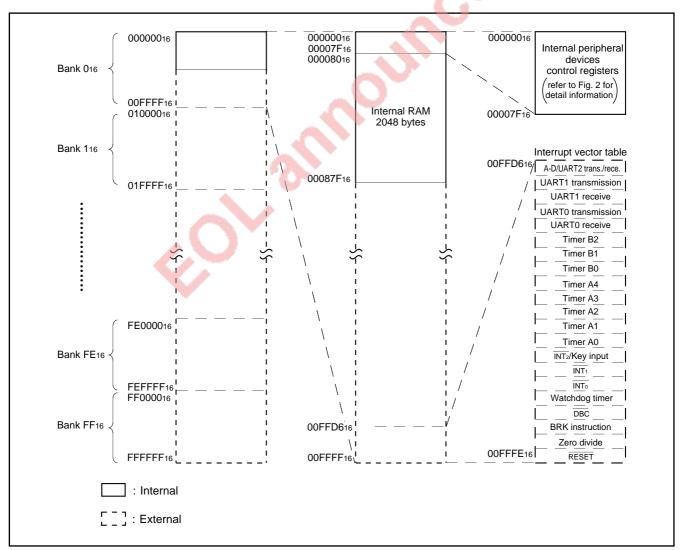


Fig. 1 Memory map





ress (Hex	adecimal notation)	Address (Hex	adecimal notation)
000000		000040	Count start flag
000001		000041	
000002	Port P0 register	000042	One-shot start flag
000003	Port P1 register	000043	
000004	Port P0 direction register	000044	Up-down flag
000005	Port P1 direction register	000045	
000006	Port P2 register	000046	Timer A0 register
000007	Port P3 register	000047	
800000	Port P2 direction register	000048	Timer A1 register
000009	Port P3 direction register	000049	
A00000	Port P4 register	00004A	Timer A2 register
00000B	Port P5 register	00004B	
00000C	Port P5 direction register	00004C	Timer A3 register
00000D 00000E	Port P5 direction register Port P6 register	00004D 00004E	
00000E	Port P7 register	00004E	Timer A4 register
000001	Port P6 direction register	00004F	
000010	Port P7 direction register	000051	Timer B0 register
000011	Port P8 register	000051	
000012		000052	Timer B1 register
000013	Port P8 direction register	000054	W
000015	3	000055	Timer B2 register
000016		000056	Timer A0 mode register
000017		000057	Timer A1 mode register
000018		000058	Timer A2 mode register
000019		000059	Timer A3 mode register
00001A		00005A	Timer A4 mode register
00001B		00005B	Timer B0 mode register
00001C	Pulse output data register 1	00005C	Timer B1 mode register
00001D	Pulse output data register 0	00005D	Timer B2 mode register
00001E	A-D control register 0	00005E	Processor mode register 0
00001F	A-D control register 1	00005F	Processor mode register 1
000020	A-D register 0	000060	Watchdog timer register
000021	7. 2 Tog.oto. 0	000061	Watchdog timer frequency selection flag
000022	A-D register 1	000062	Waveform output mode register
000023	0	000063	Reserved area (Note)
000024	A-D register 2	000064	UART2 transmit/receive mode register
000025		000065	UART2 baud rate register (BRG2)
000026 000027	A-D register 3	000066 000067	UART2 transmission buffer register
000028	A-D register 4	000068	UART2 transmit/receive control register 0
000029		000069	UART2 transmit/receive control register 1
00002A	A-D register 5	00006A	UART2 receive buffer register
00002B		00006B	Oscillation circuit control register 0
00002C 00002D	A-D register 6	00006C	Oscillation circuit control register 0 Port function control register
00002D 00002E		00006D 00006E	Serial transmit control register
00002E	A-D register 7	00006E	Oscillation circuit control register 1
000021	UART 0 transmit/receive mode register	000070	A-D/UART2 trans./rece. interrupt control register
000030	UART 0 baud rate register (BRG0)	000070	UART 0 transmission interrupt control register
000031		000071	UART 0 receive interrupt control register
000032	UART 0 transmission buffer register	000072	UART 1 transmission interrupt control register
000033	UART 0 transmit/receive control register 0	000074	UART 1 receive interrupt control register
000035	UART 0 transmit/receive control register 1	000075	Timer A0 interrupt control register
000036		000076	Timer A1 interrupt control register
000037	UART 0 receive buffer register	000077	Timer A2 interrupt control register
000038	UART 1 transmit/receive mode register	000078	Timer A3 interrupt control register
000039	UART 1 baud rate register (BRG1)	000079	Timer A4 interrupt control register
00003A		00007A	Timer B0 interrupt control register
00003B	UART 1 transmission buffer register	00007B	Timer B1 interrupt control register
00003C	UART 1 transmit/receive control register 0	00007C	Timer B2 interrupt control register
00003D	UART 1 transmit/receive control register 1	00007D	INTo interrupt control register
00003E	LIART 1 receive buffer register	00007E	INT1 interrupt control register
00003F	UART 1 receive buffer register	00007F	INT2/Key input interrupt control register

Fig. 2 Location of internal peripheral devices and interrupt control registers





Pulse output port mode

The pulse motor drive waveform can be output by using plural internal timer A.

Figure 3 shows a block diagram for pulse output port mode. In the pulse output port mode, two pairs of four-bit pulse output ports are used. Whether using pulse output port or not can be selected by waveform output selection bit (bit 0, bit 1) of waveform output mode register (6216 address) shown in Figure 4. When bit 0 of waveform output selection bit is set to "1", RTP10, RTP11, RTP12, and RTP13 are used as pulse output ports, and when bit 1 of waveform output selection bit is set to "1", RTP00, RTP01, RTP02, and RTP03 are used as pulse output ports. When bits 1 and 0 of waveform output selection bit are set to "1", RTP10, RTP11, RTP12, and RTP13, and RTP00, RTP01, RTP02, and RTP03 are used as pulse output ports. The ports not used as pulse output ports can be used as normal parallel ports, timer input/output or key input interruput input.

In the pulse output port mode, set timers A0 and A2 to timer mode as timers A0 and A2 are used. Figure 5 shows the bit configuration of timer A0, A2 mode registers in pulse output port mode.

Data can be set in each bit of the pulse output data register corresponding to four ports selected as pulse output ports. Figure 6

shows the bit configuration of the pulse output data register. The contents of the pulse output data register 1 (low-order four bits of 1C16 address) corresponding to RTP10, RTP11, RTP12, and RTP13 is output to the ports each time the counter of timer A2 becomes 000016. The contents of the pulse output data register 0 (low-order four bits of 1D16 address) corresponding to RTP00, RTP01, RTP02, and RTP03 is output to the ports each time the counter of timer A0 becomes 000016.

Figure 7 shows example of waveforms in pulse output port mode. When "0" is written to a specified bit of the pulse output data register, "L" level is output to the corresponding pulse output port when the counter of corresponding timer becomes 000016, and when "1" is written, "H" level is output to the pulse output port.

Pulse width modulation can be applied to each pulse output port. Since pulse width modulation involves the use of timers A1 and A3, activate these timers in pulse width modulation mode.

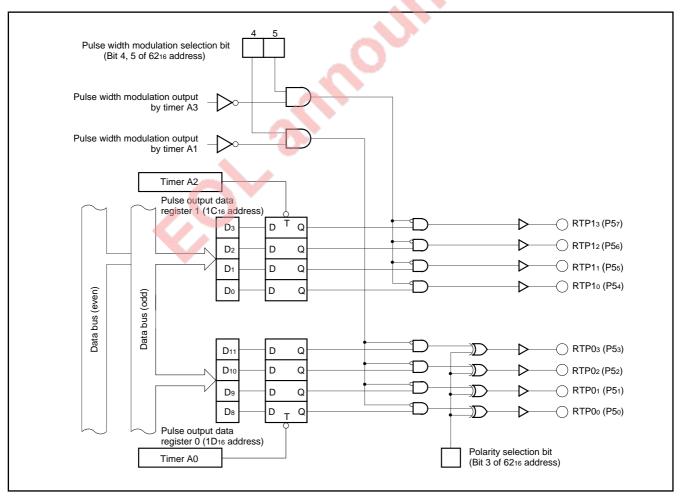


Fig. 3 Block diagram for pulse output port mode





RTP10, RTP11, RTP12, and RTP13 are applied pulse width modulation by timer A3 by setting the pulse width modulation selection bit by timer A3 (bit 5) of the waveform output mode register to "1".

RTP00, RTP01, RTP02, and RTP03 are applied pulse width modulation by timer A1 by setting the pulse width modulation selection bit by timer A1 (bit 4) of the waveform output mode register to "1".

The contents of the pulse output data register 0 can be reversed and output to pulse output ports RTP00, RTP01, RTP02, and RTP03 by the polarity selection bit (bit 3) of the waveform output mode register. When the polarity selection bit is "0", the contents of the pulse output data register 0 is output unchangeably, and when "1", the contents of the pulse output data register 0 is reversed and output. When pulse width modulation is applied, likewise the polarity reverse to pulse width modulation can be selected by the polarity selection bit.

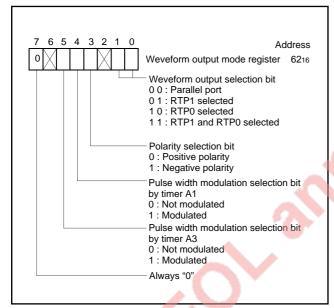


Fig. 4 Waveform output mode register bit configuration

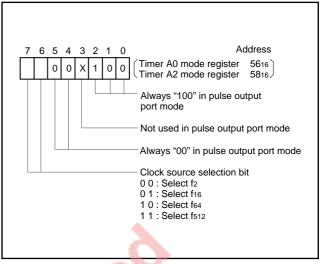


Fig. 5 Timer A0, A2 mode register bit configuration in pulse output port mode

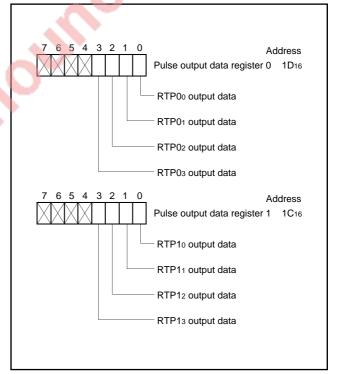


Fig. 6 Pulse output data register bit configuration



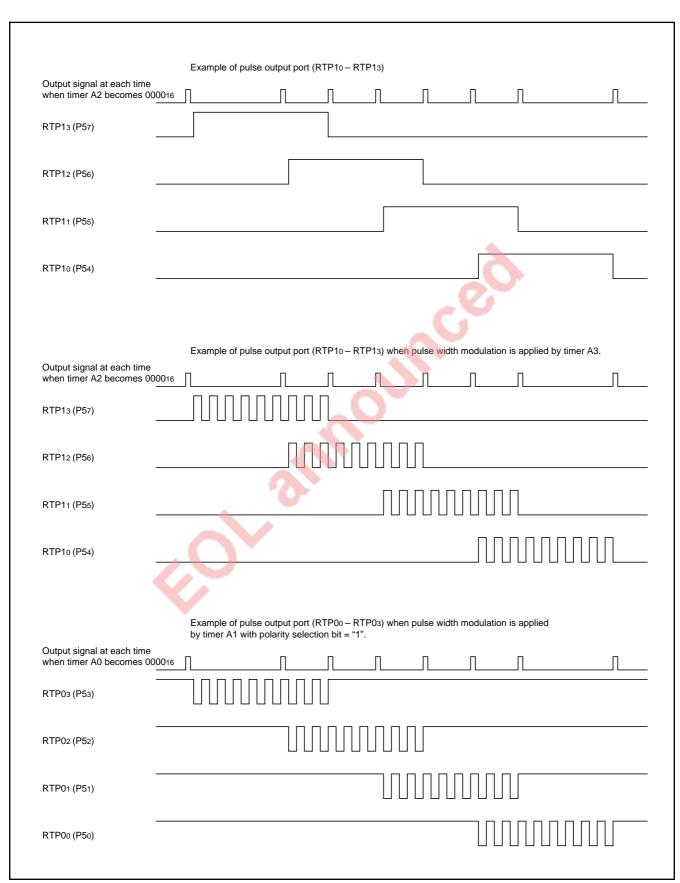


Fig. 7 Example of waveforms in pulse output port mode





PROCESSOR MODE

The bits 0 of processor mode register 0 as shown in Figure 8 is used to select which mode of microprocessor mode, and evaluation chip mode

Figure 9 shows functions of P0o/Ao to P47 pins in each mode.

The external memory area also changes when the mode changes. Figure 10 shows the memory map for each mode.

The accessing of the external memory is affected by the BYTE pin, the bit 2 (wait bit) of processor mode register 0, and bit 0 (wait selection bit) of processor mode register 1.

• BYTE pin

When accessing the external memory, the level of the BYTE pin is used to determine whether to use the data bus as 8-bit width or 16-bit width.

The data bus width is 8 bits when the level of the BYTE pin is "H", and P2o/A16/D0 to P27/A23/D7 pins become the data I/O pins.

The data bus width is 16 bits when the level of the BYTE pin is "L", and both P20/A16/D0 to P27/A23/D7 pins and P10/A8/D8 to P17/A15/ D15 pins become the data I/O pins.

When accessing the internal memory, the data bus width is always 16 bits regardless of the BYTE pin level.

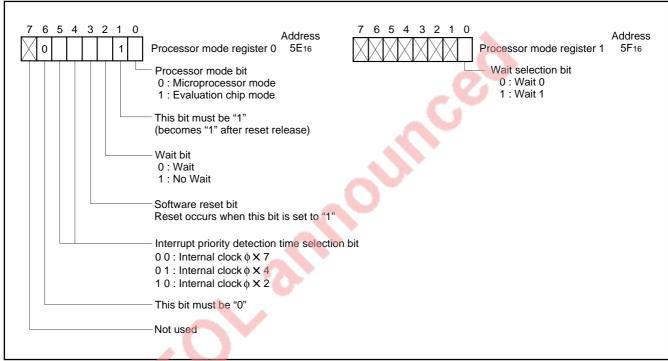


Fig. 8 Processor mode register bit configuration





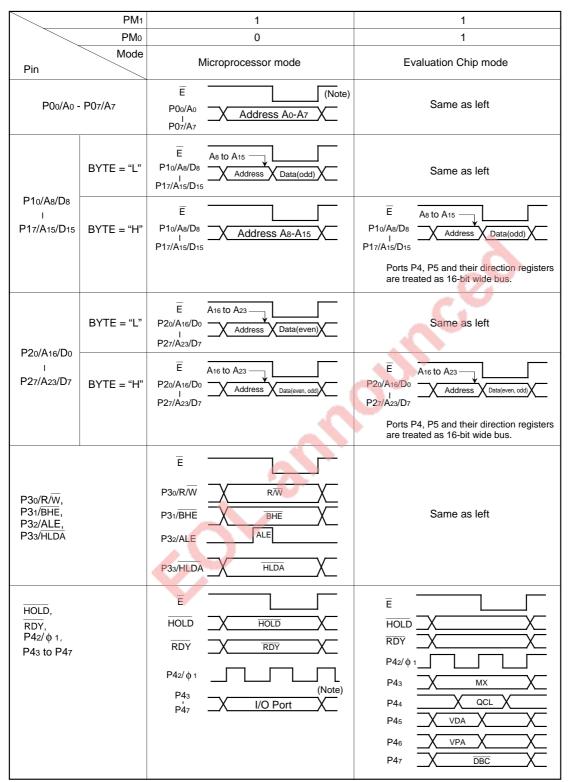


Fig. 9 Relationship between pins P0o/Ao to P47 and processor modes

Note. The signal output disable selection bit (bit 6 of the oscillation circuit control register 0) can stop the ϕ 1 output in the microprocessor mode. In the microprocessor mode, signal \overline{E} can also be fixed to "H" when the internal memory area is accessed.





Wait bit

As shown in Figure 11, when the external memory area is accessed with the processor mode register 0 (address 5E₁₆) bit 2 (wait bit) cleared to "0", the access time can be extended compared with no wait (the wait bit is "1").

The access time is extended in two ways and this is selected with bit 0 (wait selection bit) of processor mode register 1 (address 5F₁₆).

When this bit is "1", the access time is 1.5 times compared to that for no wait. When this bit is "0", the access time is twice compared to that for no wait.

At reset, the wait bit and the wait selection bit are "0".

The accessing of internal memory area is performed in no wait mode regardless of the wait bit.

The processor modes are described below.

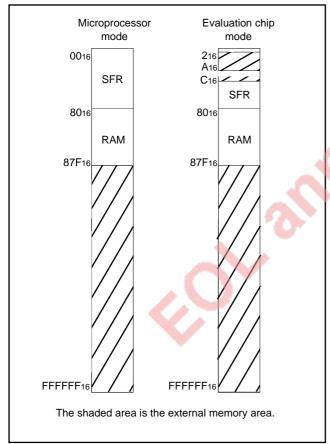


Fig. 10 External memory area for each processor mode

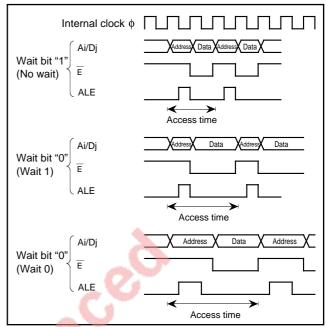


Fig. 11 Relationship between wait bit, wait selection bit, and access time

(1) Microprocessor mode [10]

Microprocessor mode is entered by connecting the CNVss pin to Vcc and starting from reset.

Signal \overline{E} is output from pin \overline{E} and is "L" during the data/instruction code read or data write term. When the internal memory area is read or written, \overline{E} can be fixed to "H" by setting the signal output disable selection bit (bit 6 of oscillation circuit control register 0) to "1".

P00/A0 to P07/A7 pins become address output pins.

P10/A8/D8 to P17/A15/D15 pins have two functions depending on the level of the BYTE pin.

When the BYTE pin level is "L", P1o/A8/D8 to P1r/A15/D15 pins function as an address output pin while \overline{E} is "H" and as an odd address data I/O pin while \overline{E} is "L". However, if an internal memory is read, external data is ignored while \overline{E} is "L".

When the BYTE pin level is "H", P10/A8/D8 to P17/A15/D15 pins function as an address output pin.

When the BYTE pin level is "L", P2o/A₁₆/D₀ to P2r/A₂₃/D₇ pins function as an address output pin while \overline{E} is "H" and as an even address data I/O pin while \overline{E} is "L". However, if an internal memory is read, external data is ignored while \overline{E} is "L".

 $R\overline{W}$ is a read /write signal which indicates a read when it is "H" and a write when it is "I"

 $\overline{\text{BHE}}$ is a byte high enable signal which indicates that an odd address is accessed when it is "L".

Therefore, two bytes at even and odd addresses are accessed simultaneously if address Ao is "L" and $\overline{\rm BHE}$ is "L".

ALE is an address latch enable signal used to latch the address signal from a multiplexed signal of address and data. The latch is transparent while ALE is "H" to let the address signal pass through and held while ALE is "L".



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HLDA is a hold acknowledge signal and is used to notify externally when the microcomputer receives $\overline{\text{HOLD}}$ input and enters hold state. $\overline{\text{HOLD}}$ is a hold request signal. It is an input signal used to put the microcomputer in hold state. $\overline{\text{HOLD}}$ input is accepted when the internal clock φ falls from "H" level to "L" level while the bus is not used. P0o/Ao to P07/A7 pins, P1o/As/D8 to P17/A15/D15 pins, P2o/A16/Do to P27/A23/D7 pins, P3o/R/W pin, and P31/BHE pin are floating while the microcomputer stays in hold state. These pins are floating after one cycle of the internal clock φ later than $\overline{\text{HLDA}}$ signal changes to "L" level. At the removing of hold state, these ports are removed from floating state after one cycle of internal clock φ later than $\overline{\text{HLDA}}$ signal changes to "H" level.

 \overline{RDY} is a ready signal. If this signal goes "L", the internal clock ϕ stops at "L". \overline{RDY} is used when slow external memory is attached. P42/ ϕ 1 pin is an output pin for clock ϕ 1. The ϕ 1 output is independent of \overline{RDY} and does not stop even when internal clock ϕ stops because of "L" input to the \overline{RDY} pin. As shown in Table 2, ϕ 1 output can also be stopped with the signal output disable selection bit "1". In this case, write "1" to the port P42 direction register.

(2) Evaluation chip mode [11]

Evaluation chip mode is entered by applying voltage twice the Vcc voltage to the CNVss pin. This mode is normally used for evaluation tools.

The functions of \overline{E} , P0o/Ao to P07/A7 pins, R/ \overline{W} , \overline{BHE} , ALE, and \overline{HLDA} are the same as those in microprocessor mode.

P10/A8/D8 to P17/A15/D15 pins function as address output pins while \overline{E} is "H" and as data I/O pin \overline{of} odd addresses while \overline{E} is "L" regardless of the BYTE pin level. However, if an internal memory is read, external data is ignored while \overline{E} is "L". P20/A16/D0 to P27/A23/D7 pins function as address output pins while \overline{E} is "H" and as data I/O pin of even addresses while \overline{E} is "L" when the BYTE pin level is "L". However, if an internal memory is read, external data is ignored while \overline{E} is "L". When the BYTE pin level is "H" or 2•Vcc, port P2 functions as an address output pin while \overline{E} is "H" and as data I/O pin of even and odd addresses while \overline{E} is "L". However, if an internal memory is read, external data is ignored while \overline{E} is "L".

Port P4 and its data direction which are located at address 0A₁₆ and 0C₁₆ are treated differently in evaluation chip mode. When these

addresses are accessed, the data bus width is treated as 16 bits regardless of the BYTE pin level, and the access cycle is treated as internal memory regardless of the wait bit.

The functions of $\overline{\text{HOLD}}$ and $\overline{\text{RDY}}$ are the same as those in microprocessor mode. Clock ϕ 1 from P42/ ϕ 1 pin is always output regardless of signal output disable selection bit.

Ports P43 to P46 become MX, QCL, VDA, and VPA output pins respectively. Port P47 becomes the $\overline{\text{DBC}}$ input pin.

The MX signal normally contents of flag m, but the contents of flag x is output if the CPU is using flag x.

QCL is the queue buffer clear signal. It becomes "H" when the instruction queue buffer is cleared, for example, when a jump instruction is executed.

VDA is the valid data address signal. It becomes "H" while the CPU is reading data from data buffer or writing data to data buffer. It also becomes "H" when the first byte of the instruction (operation code) is read from the instruction queue buffer.

VPA is the valid program address signal. It becomes "H" while the CPU is reading an instruction code from the instruction queue buffer. DBC is the debug control signal and is used for debugging. Table 1 shows the relationship between the CNVss pin input levels and processor modes.

Table 1. Relationship between CNVss pin input levels and processor modes

CNVss	Mode	Description
		Microprocessor mode upon starting after reset.
2 • Vcc	 Evaluation chip 	Evaluation chip mode only.

Table 2. Function of signal output disable selection bit CM6 (bit 6 of oscillation circuit control register 0)

Processor mode	Pin	Function			
1 10cessor mode	""	CM6 = "0"	CM6 = "1"		
	Ē	E is output when the internal/external memory area is accessed.	E is output only when the external memory area is accessed.		
Microprocessor mode		After WIT/STP instruction is executed, "H" is output.	"L" is output after WIT/STP instruction is executed. * Standby state selection bit (bit 0 of port function control register) must be set to "1".		
	ф 1	Clock φ 1 is output.	"H"or "L" is output. (Output the content of P42 latch.) * Port P42 direction register must be set to "1".		

Note. Functions shown in Table 2 cannot be emulated in a debugger.





RESET CIRCUIT

The microcomputer is released from the reset state when the $\overline{\text{RESET}}$ pin is returned to "H" level after holding it at "L" level with the power source voltage at 5 V \pm 10 %. Program execution starts at the address formed by setting address A23 – A16 to 0016, A15 – A8 to the contents of address FFFF16, and A7 – A0 to the contents of address FFFE16. Figure 12 shows the status of the internal registers during reset. Figure 13 shows an example of a reset circuit. If the stabilized clock

is input from the external to the main-clock oscillation circuit, the reset input voltage must be 0.9 V or less when the power source voltage reaches 4.5 V. If a resonator/oscillator is connected to the main-clock oscillation circuit, change the reset input voltage from "L" to "H" after the main-clock oscillation is fully stabilized.

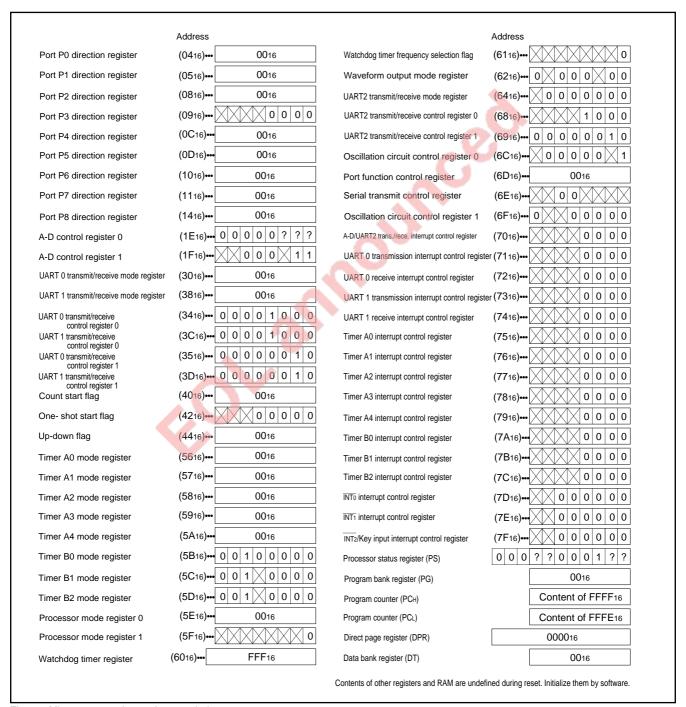


Fig. 12 Microcomputer internal status during reset





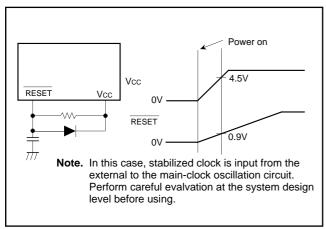


Fig. 13 Example of a reset circuit

ADDRESSING MODES

The M37733S4BFP has 28 powerful addressing modes. Refer to the MITSUBISHI SEMICONDUCTORS DATA BOOK SINGLE - CHIP 16-BIT MICROCOMPUTERS for the details of each addressing mode.

MACHINE INSTRUCTION LIST

The M37733S4BFP has 103 machine instructions. Refer to the MITSUBISHI SEMICONDUCTORS DATA BOOK SINGLE - CHIP 16-BIT MICROCOMPUTERS for details.





ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Conditions	Ratings	Unit
Vcc	Power source voltage		-0.3 to +7	V
AVcc	Analog power source voltage		-0.3 to +7	V
Vı	Input voltage RESET, CNVss, BYTE		-0.3 to +12	V
Vı	Input voltage P10/A8/D8 – P17/A15/D15, P20/A16/D0 – P27/A23/D7, P43 – P47, P50 – P57, P60 – P67, P70 – P77, P80 – P87, VREF, XIN, HOLD, RDY		-0.3 to Vcc + 0.3	V
Vo	Output voltage P00/A0 – P07/A7, P10/A8/D8 – P17/A15/D15, P20/A16/D0 – P27/A23/D7, P30/R/W, P31/BHE, P32/ALE, P33/HLDA, P42/ ф 1, P43 – P47, P50 – P57, P60 – P67, P70 – P77, P80 – P87, XOUT, E		-0.3 to Vcc + 0.3	V
Pd	Power dissipation	Ta = 25 °C	300	mW
Topr	Operating temperature		-20 to +85	°C
Tstg	Storage temperature		-40 to +150	°C

RECOMMENDED OPERATING CONDITIONS (Vcc = 5 V ± 10 %, Ta = -20 to +85 °C, unless otherwise noted)

Currente est	Deremeter		Limits		11
Symbol	Parameter	Min.	Тур.	Max.	Unit
\	f(XIN): Operating	4.5	5.0	5.5	V
Vcc	Power source voltage f(XIN): Stopped, f(XCIN) = 32.768 kHz	2.7		5.5	·
AVcc	Analog power source voltage		Vcc		V
Vss	Power source voltage		0		V
AVss	Analog power source voltage		0		V
VIH	High-level input voltage HOLD, RDY, P43 – P47, P50 – P57, P60 – P67, P70 – P77, P80 – P87, XIN, RESET, CNVss, BYTE, XCIN (Note 3)	0.8 Vcc		Vcc	V
VIH	High-level input voltage P1o/As/Ds – P17/A15/D15, P2o/A16/D0 – P27/A23/D7	0.5 Vcc		Vcc	V
VIL	Low-level input voltage HOLD, RDY, P43 – P47, P50 – P57, P60 – P67, P70 – P77, P80 – P87, XIN, RESET, CNVss, BYTE, XCIN (Note 3)	0		0.2Vcc	V
VIL	Low-level input voltage P1o/As/Ds - P17/A15/D15, P2o/A16/Do - P27/A23/D7	0		0.16Vcc	V
IOH(peak)	High-level peak output current P0o/Ao – P07/A7, P1o/As/D8 – P17/A15/D15, P2o/A16/D0 – P27/A23/D7, P3o/R/W, P31/BHE, P32/ALE, P33/HLDA, P42/ \$\phi\$1, P43 – P47, P50 – P57, P60 – P67, P70 – P75, P80 – P87			-10	mA
IOH(avg)	High-level average output current P0o/Ao – P07/A7, P1o/As/Ds – P17/A15/D15, P2o/A16/Do – P27/A23/D7, P3o/R/W, P31/BHE, P32/ALE, P33/HLDA, P42/ ф 1, P43 – P47, P50 – P57, P60 – P67, P70 – P75, P80 – P87			-5	mA
lOL(peak)	Low-level peak output current P0o/Ao – P07/A7, P1o/Ae/D8 – P17/A15/D15, P2o/A16/D0 – P27/A23/D7, P3o/R/W, P31/BHE, P32/ALE, P33/HLDA, P42/ \$\phi\$ 1, P43, P54 – P57, P6o – P67, P7o – P75, P8o – P87			10	mA
IOL(peak)	Low-level peak output current P44 – P47, P50 – P53			20	mA
lOL(avg)	Low-level average output current P0o/Ao – P07/A7, P1o/Ae/De – P17/A15/D15, P2o/A16/Do – P27/A23/D7, P3o/R/W, P31/BHE, P32/ALE, P33/HLDA, P42/ \$\phi\$ 1, P43, P54 – P57, P6o – P67, P7o – P75, P8o – P87			5	mA
IOL(avg)	Low-level average output current P44 – P47, P50 – P53			15	mA
f(XIN)	Main-clock oscillation frequency (Note 4)			25	MHz
f(Xcin)	Sub-clock oscillation frequency		32.768	50	kHz

 $\textbf{Notes 1.} \ \, \text{Average output current is the average value of a 100 ms interval}.$

- 2. The sum of IoL(peak) for ports P0o/Ao P07/A7, P1o/Aa/Da P17/A15/D15, P2o/A16/Do P27/A23/D7, P3o/R/W, P31/BHE, P32/ALE, P33/HLDA and P8 must be 80 mA or less, the sum of IoH(peak) for ports P0o/Ao P07/A7, P1o/Aa/Da P17/A15/D15, P2o/A16/Do P27/A23/D7, P3o/R/W, P31/BHE, P32/ALE, P33/HLDA and P8 must be 80 mA or less, the sum of IoL(peak) for ports P4, P5, P6, and P7 must be 100 mA or less, and the sum of IoH(peak) for ports P4, P5, P6, and P7 must be 80 mA or less.
- 3. Limits VIH and VIL for XCIN are applied when the sub clock external input selection bit = "1".
- 4. The maximum value of f(XIN) = 12.5 MHz when the main clock division selection bit = "1".





ELECTRICAL CHARACTERISTICS (Vcc = 5 V, Vss = 0 V, Ta = -20 to +85 °C, f(XIN) = 25 MHz, unless otherwise noted)

Symbol	Doromotor	Test conditions		Limits		11
Symbol	Parameter	rest conditions	Min.	Тур.	Max.	Unit
Vон	$\label{eq:high-level output voltage P00/A0 - P07/A7, P10/A8/D8 - P17/A15/D15,} \\ P20/A16/D0 - P27/A23/D7, P33/HLDA, P42/ $$ $$ $$ $P43 - P47, P50 - P57, P60 - P67, P70 - P77, \\ P80 - P87 \\ \end{tabular}$	IOH = -10 mA	3			V
Vон	High-level output voltage P0 ₀ /A ₀ – P0 ₇ /A ₇ , P1 ₀ /A ₈ /D ₈ – P1 ₇ /A ₁₅ /D ₁₅ , P2 ₀ /A ₁₆ /D ₀ – P2 ₇ /A ₂₃ /D ₇ , P3 ₃ /HLDA, P4 ₂ / φ 1	IOH = -400 μ A	4.7			V
Vон	High-level output voltage P30/R/W, P31/BHE, P32/ALE	IOH = -10 mA IOH = -400 μ A	3.1 4.8			V
Vон	High-level output voltage E	IOH = -10 mA IOH = -400 μ A	3.4 4.8			V
VoL	$ \begin{array}{llllllllllllllllllllllllllllllllllll$	IOL = 10 mA	7.0		2	V
Vol	Low-level output voltage P44 – P47, P50 – P53	IoL = 20 mA			2	V
VoL	Low-level output voltage P0o/Ao – P07/A7, P1o/As/Ds – P17/A15/D15, P2o/A16/Do – P27/A23/D7, P33/HLDA, P42/ ф 1	IOL = 2 mA	7		0.45	V
Vol	Low-level output voltage P3o/R/W, P31/BHE, P32/ALE	IOL = 10 mA			1.9 0.43	V
Vol	Low-level output voltage E	IOL = 10 mA			1.6	V
VT+ - VT-	Hysteresis HOLD, RDY, TA0IN – TA4IN, TB0IN – TB2IN, INTo – INT2, ADTRG, CTS0, CTS1, CTS2, CLK0, CLK1, CLK2, Klo – Kls		0.4		1	V
$V_{T+} - V_{T-}$	Hysteresis RESET		0.2		0.5	V
VT+ - VT-	Hysteresis XIN	Vcc = 5 V	0.1		0.4	V
VT+ - VT-	Hysteresis Xcın (When external clock is input)		0.1		0.4	V
Іін	High-level input current P10/As/D8 – P17/A15/D15, P20/A16/D0 – P27/A23/D7, P43 – P47, P50 – P57, P60 – P67, P70 – P77, P80 – P87, XIN, RESET, CNVss, BYTE	VI = 5 V			5	μΑ
lıL	Low-level input current P1o/As/D8 – P17/A15/D15, P2o/A16/D0 – P27/A23/D7, P43 – P47, P50 – P53, P60, P61, P65 – P67, P70 – P77, P80 – P87, XIN, RESET, CNVss, BYTE	VI = 0 V			-5	μА
lıL	Low-level input current P54 – P57, P62 – P64	V _I = 0 V, without a pull-up transistor			-5	μА
	200 10701 input out of 1 07, 1 02 1 04	V _I = 0 V, with a pull-up transistor	-0.25	-0.5	-1.0	mA
VRAM	RAM hold voltage	When clock is stopped	2			V





ELECTRICAL CHARACTERISTICS (Vcc = 5 V, Vss = 0 V, Ta = -20 to +85 °C, unless otherwise noted)

Symbol	Parameter		Test conditions		Limits		11
Cymbol	Tarameter		T GSt GOTIGITIONS	Min.	Тур.	Max.	Unit
			Vcc = 5 V, f(XIN) = 25 MHz (square waveform), (f(f2) = 12.5 MHz), f(XCIN) = 32.768 kHz, in operating (Note 1)		11.4	22.8	mA
			Vcc = 5 V, f(XIN) = 25 MHz (square waveform), (f(f2) = 1.5625 MHz), f(XCIN) = Stopped, in operating (Note 1)		1.6	3.2	mA
Icc	Power source current	When external bus is in use, output pins are open, and	$\label{eq:vcc} \begin{array}{l} \text{Vcc} = 5 \text{ V}, \\ \text{f(XIN)} = 25 \text{ MHz (square waveform)}, \\ \text{f(XcIN)} = 32.768 \text{ kHz}, \\ \text{when a WIT instruction is executed (Note 2)} \end{array}$		10	20	μΑ
otr	other pins are Vss.	Vcc = 5 V, f(XIN) = Stopped, f(XCIN) = 32.768 kHz, in operating (Note 3)	0	60	120	μΑ	
		Vcc = 5 V, f(X N) = Stopped, f(X N) = 32.768 kHz, when a WIT instruction is executed (Note 4)		5	10	μΑ	
			Ta = 25 °C, when clock is stopped			1	μΑ
			Ta = 85 °C, when clock is stopped			20	μΑ

Notes 1. This applies when the main clock external input selection bit = "1", the main clock division selection bit = "0", and the signal output stop bit = "1".

- 2. This applies when the main clock external input selection bit = "1" and the system clock stop bit at wait state = "1".
- 3. This applies when CPU and the clock timer are operating with the sub clock (32.768 kHz) selected as the system clock.
- 4. This applies when the Xcout drivability selection bit = "0" and the system clock stop bit at wait state = "1".

A-D CONVERTER CHARACTERISTICS

(Vcc = AVcc = 5 V, Vss = AVss = 0 V, Ta = -20 to +85 °C, f(XIN) = 25 MHz, unless otherwise noted (Note))

Symbol	Parameter	Test conditions		Limits		
Syllibol	Falailletei	rest conditions	Min.	Тур.	Max.	Unit
_	Resolution	VREF = VCC			10	Bits
_	Absolute accuracy	VREF = VCC			± 3	LSB
RLADDER	Ladder resistance	VREF = VCC	10		25	kΩ
tconv	Conversion time		9.44			μs
VREF	Reference voltage		2		Vcc	V
VIA	Analog input voltage		0		VREF	V

Note. This applies when the main clock division selection bit = "0" and $f(f_2) = 12.5$ MHz.





TIMING REQUIREMENTS ($Vcc = 5 V \pm 10 \%$, Vss = 0 V, Ta = -20 to +85 °C, f(XIN) = 25 MHz, unless otherwise noted (Note 1)) **Notes 1.** This applies when the main clock division selection bit = "0" and f(fz) = 12.5 MHz.

2. Input signal's rise/fall time must be 100 ns or less, unless otherwise noted.

External clock input

Symbol	Parameter	Lin	nits	Linit
Symbol	Symbol Larameter	Min.	Max.	Unit
tc	External clock input cycle time (Note 1)	40		ns
tw(H)	External clock input high-level pulse width (Note 2)	15		ns
tw(L)	External clock input low-level pulse width (Note 2)	15		ns
tr	External clock rise time		8	ns
tf	External clock fall time		8	ns

Notes 1. When the main clock division selection bit = "1", the minimum value of tc = 80 ns.

2. When the main clock division selection bit = "1", values of tw(H) / tc and tw(L) / tc must be set to values from 0.45 through 0.55.

Microprocessor mode

Symbol	Parameter	Lir	nits	Unit
Cymbol	i didifficio	Min.	Max.	Offic
tsu(P4D-E)	Port P4 input setup time	60		ns
tsu(P5D-E)	Port P5 input setup time	60		ns
tsu(P6D-E)	Port P6 input setup time	60		ns
tsu(P7D-E)	Port P7 input setup time	60		ns
tsu(P8D-E)	Port P8 input setup time	60		ns
th(E-P4D)	Port P4 input hold time	0		ns
th(E-P5D)	Port P5 input hold time	0		ns
th(E-P6D)	Port P6 input hold time	0		ns
th(E-P7D)	Port P7 input hold time	0		ns
th(E-P8D)	Port P8 input hold time	0		ns
tsu(D-E)	Data input setup time	32		ns
tsu(RDY- ϕ 1)	RDY input setup time	55		ns
tsu(HOLD- \$\psi\$ 1)	HOLD input setup time	55		ns
th(E-D)	Data input hold time	0		ns
th(\$ 1-RDY)	RDY input hold time	0		ns
th(\$ 1-HOLD)	HOLD input hold time	0		ns





Timer A input (Count input in event counter mode)

Symbol	parameter	Limits		Linit
	parameter	Min.	Max.	Unit
tc(TA)	TAin input cycle time	80		ns
tw(TAH)	TAin input high-level pulse width	40		ns
tw(TAL)	TAin input low-level pulse width	40		ns

Timer A input (Gating input in timer mode)

Symbol	parameter	Limits		Unit
	parameter	Min.	Min. Max.	Offic
tc(TA)	TAil input cycle time (Note)	320		ns
tw(TAH)	TAil input high-level pulse width (Note)	160		ns
tw(TAL)	TAin input low-level pulse width (Note)	160		ns

Note. Limits change depending on f(XIN). Refer to "DATA FORMULAS."

Timer A input (External trigger input in one-shot pulse mode)

Symbol	parameter		Limits	Linit	
	parameter	- Salar	Min.	Max.	Unit
tc(TA)	TAil input cycle time (Note)	7	320		ns
tw(TAH)	TAil input high-level pulse width		80		ns
tw(TAL)	TAil input low-level pulse width		80		ns

Note. Limits change depending on f(XIN). Refer to "DATA FORMULAS."

Timer A input (External trigger input in pulse width modulation mode)

Symbol	parameter	Limits		Linit
Cymbol	parameter	Min.	Max.	Unit
tw(TAH)	TAin input high-level pulse width	80		ns
tw(TAL)	TAil input low-level pulse width	80		ns

Timer A input (Up-down input in event counter mode)

Symbol	parameter	Limits		Unit
	parameter	Min.	Max.	Offic
tc(UP)	TAiout input cycle time	2000		ns
tw(UPH)	TAiout input high-level pulse width	1000		ns
tw(UPL)	TAiout input low-level pulse width	1000		ns
tsu(UP-Tin)	TAiout input setup time	400		ns
th(T _{IN} -UP)	TAiout input hold time	400		ns

Timer A input (Two-phase pulse input in event counter mode)

Symbol	parameter	Lir	mits	Lloit
	parameter	Min.	Max.	Unit
tc(TA)	TAjın input cycle time	800		ns
tsu(ТАjın-ТАjоuт)	TAjın input setup time	200		ns
tsu(ТАјоит-ТАји)	TAjout input setup time	200		ns





Timer B input (Count input in event counter mode)

Symbol	Parameter	Limits		Unit
Symbol	i didilicici	Min.	Max.	Unit
tc(TB)	TBilN input cycle time (one edge count)	80		ns
tw(TBH)	TBiln input high-level pulse width (one edge count)	40		ns
tw(TBL)	TBiln input low-level pulse width (one edge count)	40		ns
tc(TB)	TBiin input cycle time (both edges count)	160		ns
tw(TBH)	TBiln input high-level pulse width (both edges count)	80		ns
tw(TBL)	TBiln input low-level pulse width (both edges count)	80		ns

Timer B input (Pulse period measurement mode)

Symbol	Parameter	Limits		Linit
	i arameter	Min. Max.	Max.	Unit
tc(TB)	TBin input cycle time (Note)	320		ns
tw(TBH)	TBin input high-level pulse width (Note)	160		ns
tw(TBL)	TBin input low-level pulse width (Note)	160		ns

Note. Limits change depending on f(XIN). Refer to "DATA FORMULAS."

Timer B input (Pulse width measurement mode)

Symbol	Parameter	Liı	Limits	
	i alametei	Min.	Max.	Unit
tc(TB)	TBin input cycle time (Note)	320		ns
tw(TBH)	TBin input high-level pulse width (Note)	160		ns
tw(TBL)	TBiın input low-level pulse width (Note)	160		ns

Note. Limits change depending on f(XIN). Refer to "DATA FORMULAS."

A-D trigger input

Symbol	Parameter	Limits	nits	Unit
Cymbol	i diamotoi	Min.	Max.	Offic
tc(AD)	ADTRG input cycle time (minimum allowable trigger)	1000		ns
tw(ADL)	ADTRG input low-level pulse width	125		ns

Serial I/O

Symbol	Parameter	Limits		Unit
Oymboi	Talanotoi	Min.	Max.	Offic
tc(CK)	CLKi input cycle time	200		ns
tw(CKH)	CLKi input high-level pulse width	100		ns
tw(CKL)	CLKi input low-level pulse width	100		ns
td(C-Q)	TxDi output delay time		80	ns
th(C-Q)	TxDi hold time	0		ns
tsu(D-C)	RxDi input setup time	30		ns
th(C-D)	RxDi input hold time	90		ns

External interrupt INTi input, key input interrupt Kli input

Symbol	Parameter	Lir	Unit	
	raianietei	Min.	Max.	Uill
tw(INH)	INTi input high-level pulse width	250		ns
tw(INL)	INTi input low-level pulse width	250		ns
tw(KIL)	Kli input low-level pulse width	250		ns





DATA FORMULAS

Timer A input (Gating input in timer mode)

Symbol	Parameter	Limits	Limits	
Cyrribor	i arameter	Min.	Max.	Unit
tc(TA)	TAil input cycle time	$\frac{8 \times 10^9}{2 \cdot f(f_2)}$		ns
tw(TAH)	TAiın input high-level pulse width	$\frac{4 \times 10^9}{2 \cdot f(f_2)}$		ns
tw(TAL)	TAiın input low-level pulse width	$\frac{4 \times 10^9}{2 \cdot f(f_2)}$		ns

Timer A input (External trigger input in one-shot pulse mode)

Symbol Parameter	Parameter	Limits			11
	i alametei	Min. Max.	Unit		
tc(TA)	TAil input cycle time		8 X 10 ⁹ 2 • f(f ₂)		ns

Timer B input (In pulse period measurement mode or pulse width measurement mode)

Symbol	Parameter	Limits		Unit
Cymbol	1 arameter	Min.	Max.	Uniii
tc(TB)	TBin input cycle time	$\frac{8 \times 10^9}{2 \cdot f(f_2)}$		ns
tw(TBH)	ТВіім input high-level pulse width	4 X 10° 2 • f(f ₂)		ns
tw(TBL)	TBilN input low-level pulse width	$\frac{4 \times 10^9}{2 \cdot f(f_2)}$		ns

Note. f(f2) expresses the clock f2 frequency.

For the relation to the main clock and sub clock, refer to Table 9 in data sheet "M37733MHBXXXFP".





SWITCHING CHARACTERISTICS

 $(Vcc = 5 V \pm 10 \%, Vss = 0 V, Ta = -20 to +85^{\circ}C, f(XIN) = 25 MHz, unless otherwise noted (Note))$

Microprocessor mode

Symbol	Parameter	Test conditions	Lir	mits	Unit
Symbol	i didiffetei	rest conditions	Min.	Max.	Offic
td(E-P4Q)	Port P4 data output delay time			80	ns
td(E-P5Q)	Port P5 data output delay time			80	ns
td(E-P6Q)	Port P6 data output delay time	Fig. 14		80	ns
td(E-P7Q)	Port P7 data output delay time			80	ns
td(E-P8Q)	Port P8 data output delay time			80	ns

Note. This applies when the main clock division selection bit = "0" and $f(f_2) = 12.5$ MHz.

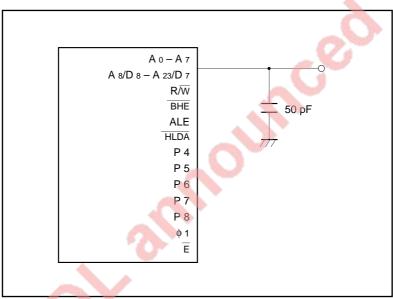


Fig. 14 Measuring circuit for each pin



Microprocessor mode

 $(Vcc = 5 V \pm 10 \%, Vss = 0 V, Ta = 25 °C, f(XIN) = 25 MHz, unless otherwise noted (Note 1))$

Symbol	Parameter	(Note2)	Test		nits	Unit
Cymbol	i arameter	Wait mode	conditions	Min.	Max.	Uniii
		No wait		12		ns
td(An–E)	Address output delay time	Wait 1		87		
		Wait 0		87		ns
+-//A F)	Address output delay time	No wait Wait 1		12		ns
td(A-E)	Address odiput delay time	Wait 0		75		ne
		vvait 0		75		ns
th(E-An)	Address hold time			18		ns
. (A) 		No wait		22		ns
tw(ALE)	ALE pulse width	Wait 1				
		Wait 0		57		ns
tsu(A-ALE)	Address sutput saturations	No wait Wait 1		5		ns
tsu(A-ALL)	Address output setup time	Wait 0		45		
		No wait				ns
th(ALE-A)	Address hold time	Wait 1	All Alle	9		ns
,	Additional time	Wait 0	Fig. 14	15		ns
		No wait		4		ns
td(ALE-E)	ALE output delay time	Wait 1				113
		Wait 0		10		ns
td(E-DQ)	Data output delay time			10	45	ns
th(E-DQ)	Data hold time	Tar		18		ns
t(EL)	=	No wait Wait 1		50		ns
tw(EL)	E pulse width	Wait 0		130		ns
tpxz(E-DZ)	Floating start delay time	wait 0			-	ns
tpzx(E-DZ)	Floating start delay time Floating release delay time			20	5	ns
φεκ(L B2)	Tribating release delay time	No wait				110
td(BHE-E)	BHE output delay time	Wait 1		12		ns
, ,	Zinz odipat dolay timo	Wait 0		87		ns
		No wait				1.0
td(R/W-E)	R/W output delay time	Wait 1		12		ns
		Wait 0		87		ns
th(E-BHE)	BHE hold time			18		ns
th(E-R/W)	R/W hold time			18		ns
td(E− φ 1)	φ 1 output delay time			0	18	ns
td(∮1–HLDA)	HLDA output delay time				50	ns

Notes 1. This applies when the main clock division selection bit = "0" and $f(f_2) = 12.5$ MHz.

2. No wait : Wait bit = "1".

Wait 1: The external memory area is accessed with wait bit = "0" and wait selection bit = "1".

Wait 0 : The external memory area is accessed with wait bit = "0" and wait selection bit = "0".





Bus timing data formulas

 $(Vcc = 5 V \pm 10 \%, Vss = 0 V, Ta = -20 to +85 °C, f(XIN) = 25 MHz (Max.), unless otherwise noted (Note 1))$

Symbol	Parameter		Limits		Unit
-,		Wait mode		Max.	Oilit
		No wait	1 X 10 ⁹ - 28		ns
td(An-E)	Address output delay time	Wait 1	2 • f(f ₂)		
, ,		Wait 0	$\frac{3 \times 10^9}{2 \cdot f(f_2)} - 33$		ns
		No weit	1 X 10 ⁹		
		No wait Wait 1	$\frac{1 \times 10^{\circ}}{2 \cdot f(f_2)} - 28$		ns
td(A-E)	Address output delay time	vvait i	3 X 10 ⁹		
		Wait 0	$\frac{3 \times 10}{2 \cdot f(f_2)} - 45$		ns
			1 ∨ 109		
th(E-An)	Address hold time		$\frac{1 \times 10^{3}}{2 \cdot f(f_2)} - 22$		ns
	No wait				
tw(ALE)	ALE pulso width	Wait 1	2 • f(f ₂)		ns
(MCL)	ALE pulse width	Wait 0	2 X 10 ⁹ - 23		ns
			2 • f(f2)		113
		No wait	$\frac{1 \times 10^9}{300} - 35$		ns
tsu(A-ALE)	Address output setup time	Wait 1	2 • f(f ₂)		
		Wait 0	$\frac{2 \times 10^9}{2 \cdot f(f_2)} - 35$		ns
		No wait	` '		
1 (A) = A)		Wait 1	9		ns
th(ALE-A)	Address hold time		$\frac{1 \times 10^9}{200} - 25$		
		Wait 0	2 • f(f ₂)		ns
		No wait	4		ns
td(ALE-E)	ALE output delay time	Wait 1			
		Wait 0	$\frac{1 \times 10^9}{2 \cdot f(f_2)} - 30$		ns
td(E-DQ)	Data output delay time		2 - 1(12)	45	ns
tu(L-DQ)	Data output delay time		1 X 10 ⁹	40	113
th(E-DQ)	Data hold time		$\frac{1}{2 \cdot f(f_2)} - 22$		ns
			2 X 10 ⁹ - 30		
tw(EL)	E pulso viidh	No wait	2 • f(f ₂)		ns
tw(EL)	E pulse width	Wait 1	$\frac{4 \times 10^9}{2 \times 10^9} - 30$		ns
		Wait 0	2 • f(f ₂)		113
tpxz(E-DZ)	Floating start delay time		4.4.4.00	5	ns
tpzx(E-DZ)	Floating release delay time		$\frac{1 \times 10^9}{2 \times 10^9} - 22$		ns
,	Trouming relication and a second seco	No wait	2 • f(f ₂)		
		Wait 1	$\frac{1 \times 10^9}{2 \cdot f(f_2)} - 28$		ns
td(BHE-E)	BHE output delay time	vvait i	2 V 109		
		Wait 0	$\frac{3 \times 10^{\circ}}{2 \cdot f(f_2)} - 33$		ns
		No wait	1 × 10 ⁹ - 28		
td(R/W-E)	R√W output delay time	Wait 1	2 • f(f ₂) - 28		ns
to(IVV L)	Tow output delay time	Wait 0	$\frac{3 \times 10^9}{2000} - 33$		ns
		, vait 0	2 • f(f2)		
th(E-BHE)	BHE hold time		$\frac{1 \times 10^9}{2}$ - 22		ns
. ,			2 • f(f2)		ļ
th(E-R/W)	R/W hold time		$\frac{1 \times 10^9}{2 \cdot f(f_2)} - 22$		ns
td(E- \$ 1)	φ 1 output delay time		0	10	ns
ω(L- ψ 1)	ψ τοαφαί delay time			18	113

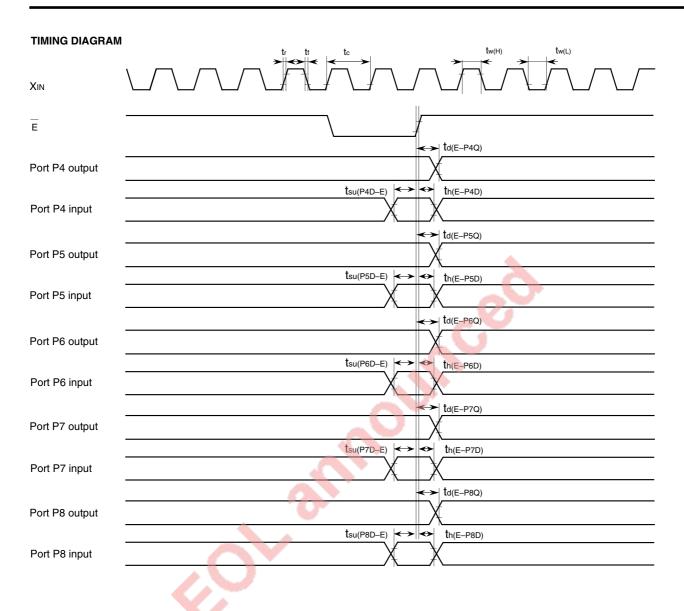
Notes 1. This applies when the main-clock division selection bit = "0".

2. f(f2) expresses the clock f2 frequency.

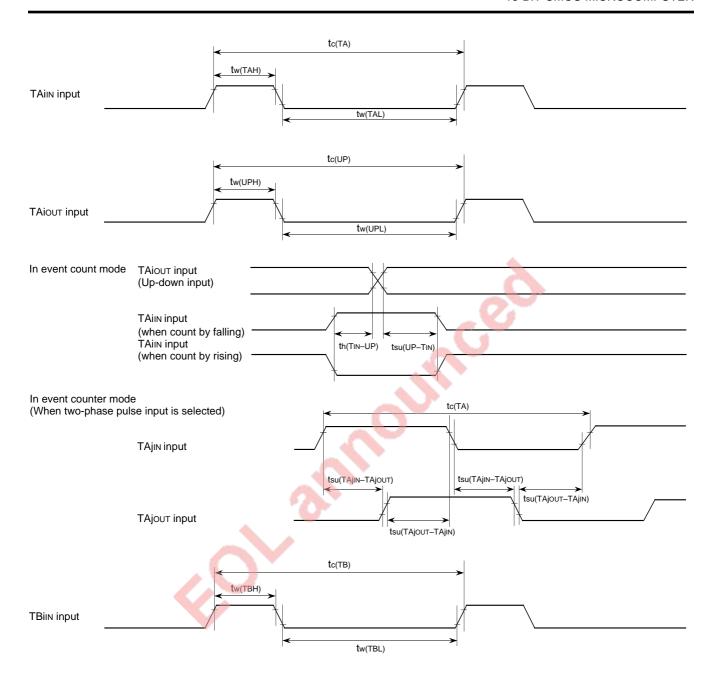
For the relation to the main clock and sub clock, refer to Table 9 in data sheet "M37733MHBXXXFP".



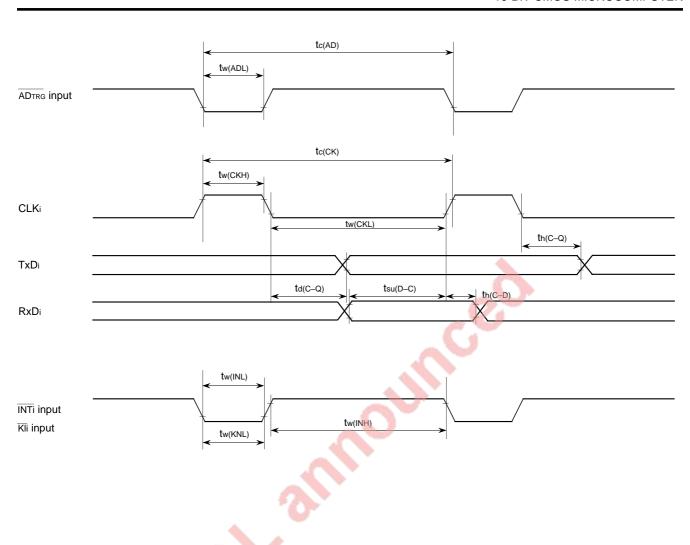




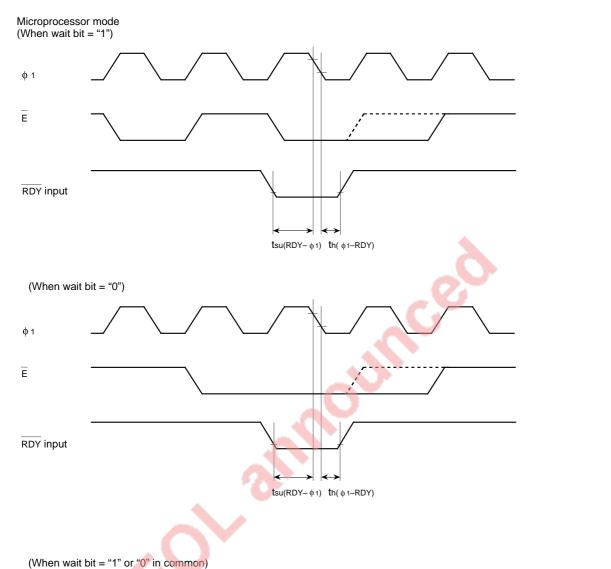


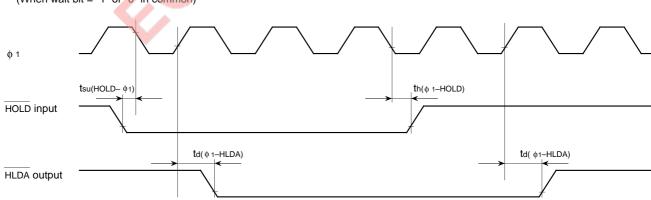








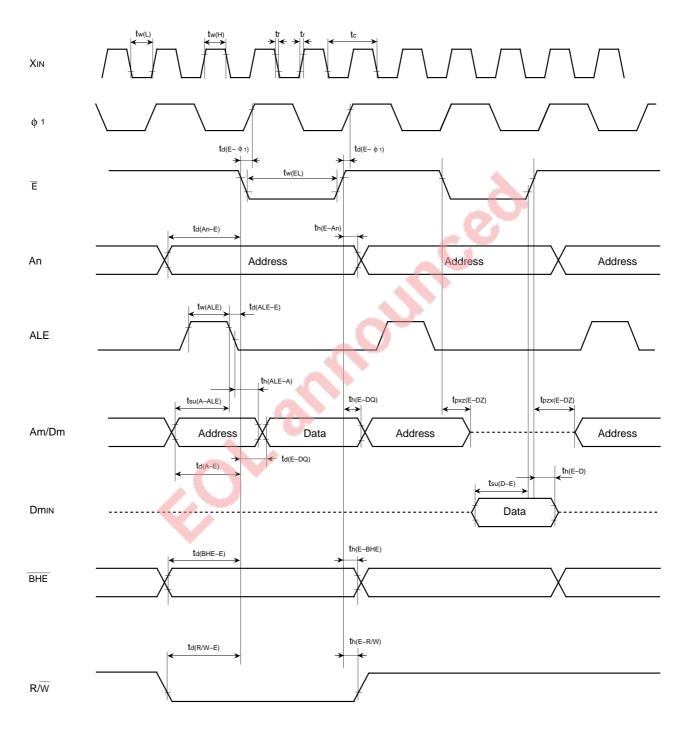




- Vcc = 5 V ± 10 %
- Input timing voltage : V_{IL} = 1.0 V, V_{IH} = 4.0 V • Output timing voltage : V_{OL} = 0.8 V, V_{OH} = 2.0 V



Microprocessor mode (No wait : When wait bit = "1")



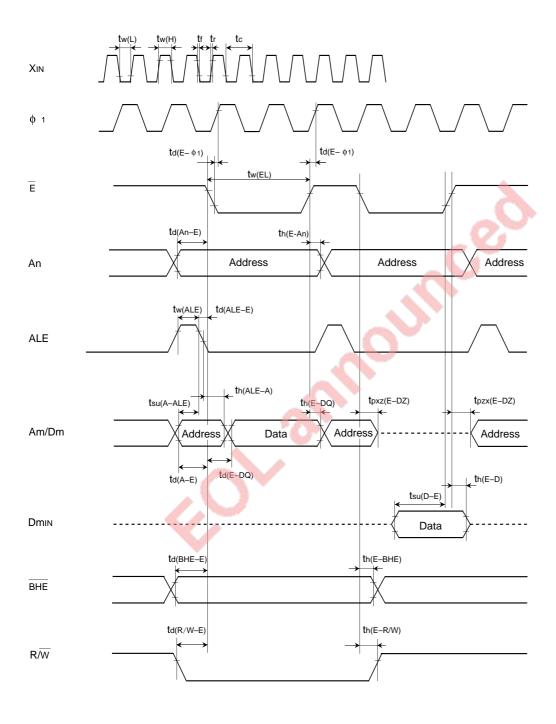
- Vcc = 5 V ± 10 %
- Output timing voltage : VoL = 0.8 V, VoH = 2.0 V
- Data input DmIN : VIL = 0.8 V, VIH = 2.5 V





Microprocessor mode

(Wait 1: The external memory area is accessed when wait bit = "0" and wait selection bit = "1".)



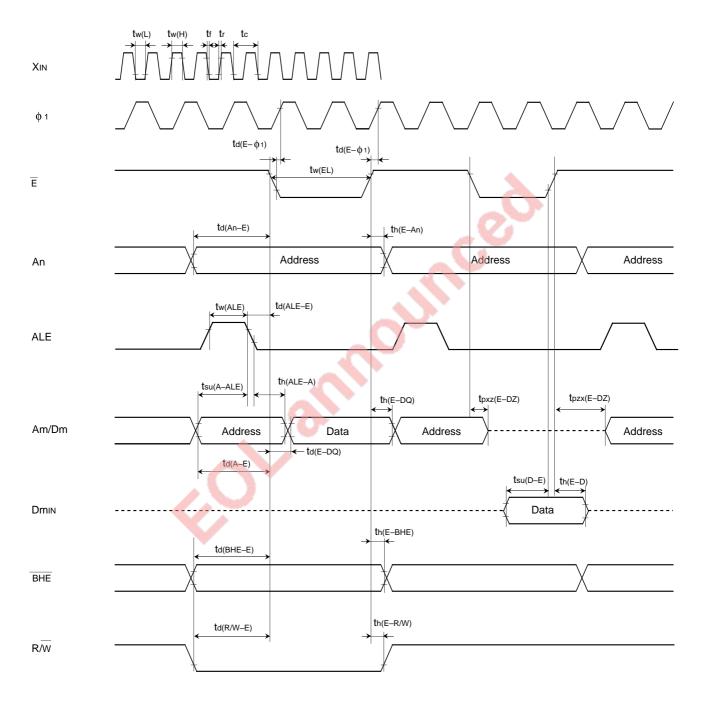
- Vcc = 5 V ± 10 %
- \bullet Output timing voltage : VoL = 0.8 V, VoH = 2.0 V
- Data input DmIN : VIL = 0.8 V, VIH = 2.5 V





Microprocessor mode

(Wait 0: The external memory area is accessed when wait bit = "0" and wait selection bit = "0".)

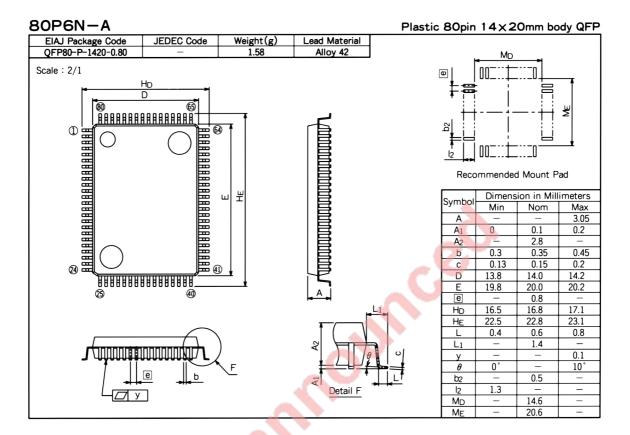


- Vcc = 5 V ± 10 %
- \bullet Output timing voltage : VoL = 0.8 V, VoH = 2.0 V
- Data input Dmin : VIL = 0.8 V, VIH = 2.5 V





PACKAGE OUTLINE





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